

## 10A High Power Schottky Barrier Rectifiers

#### ■ Features

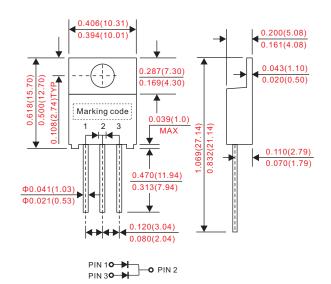
- · Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Suffix "G" indicates Halogen-free part, ex.MBR10100CTG-J.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

#### ■ Mechanical data

- Epoxy: UL94-V0 rated flame retardant.
- Case: JEDEC TO-220AB-J molded plastic body over passivated chip.
- Lead: Axial leads, solderable per MIL-STD-202, Method 208 guranteed.
- Polarity: Color band denotes cathode end.
- Mounting Position : Any.
- Weight: Approximated 2.25 gram.

## ■ Outline

TO-220AB-J



Dimensions in inches and (millimeters)

## ■ Maximum ratings and electrical characteristics

Rating at  $25^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter Marking code		Symbol	MBR10100CT-J	UNIT
			MBR10100CT	UNIT
Maximum Recurrent Peak Reverse Voltage		V <sub>RRM</sub>	100	
Maximum RMS Voltage		V <sub>RMS</sub>	70	V
Maximum DC Blocking Voltage		V <sub>DC</sub>	100	
Maximum Forward Voltage	@5.0A, T <sub>A</sub> = 25°C		0.81	
	@5.0A, T <sub>A</sub> = 125°C	V <sub>F</sub>	0.71	V
Operating Temperature		T,	-50 ~ +150	°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	Io			10	Α
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I <sub>FSM</sub>			125	Α
Reverse current	$V_R = V_{RRM} T_A = 25^{\circ}C$	l <sub>R</sub>			0.1	mA
	$V_R = V_{RRM} T_A = 125^{\circ}C$				10	
Diode junction capacitance	f=1MHz and applied 4V DC reverse voltage	C <sub>J</sub>		150		pF
Thermal resistance	Junction to ambient	R <sub>eJA</sub>		30		°C/W
Storage temperature		T <sub>STG</sub>	-55		+175	°C

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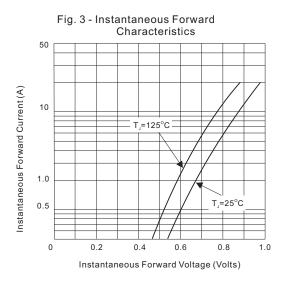
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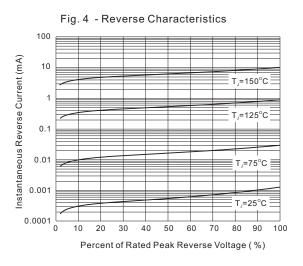


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# ■ Rating and characteristic curves

Fig.1 - Forward Current Derating Curve 12 RESISTIVE OR INDUCTIVE LOAD Average Forward Current (A) 10 8.0 6.0 4.0 single phase half wave 60Hz 2.0 resistive or inductive load 0 50 75 100 175 Lead Temperature (°C)





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